

RFMD + TriQuint = Qorvo

SGA3286Z

DC to 5000 MHz, CASCADABLE SiGe HBT MMIC AMPLIFIER

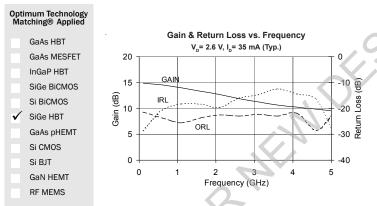
Package: SOT-86



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Product Description

The SGA3286Z is a high performance SiGe HBT MMIC Amplifier. A Darlington configuration featuring one-micron emitters provides high $F_{\rm T}$ and excellent thermal performance. The heterojunction increases breakdown voltage and minimizes leakage current between junctions. Cancellation of emitter junction non-linearities results in higher suppression of intermodulation products. At 850MHz and 35mA, the SGA3286Z typically provides +12.2dBm of 1dB compressed power using a single positive voltage supply. Only two DC-blocking capacitors, a bias resistor, and an optional RF choke are required for operation.



Features

- Broadband Operation: DC to 5000 MHz
- $\scriptstyle \bullet \ \mbox{Cascadable} \ \mbox{50} \Omega$
- Patented SiGe Technology
- Operates from Single Supply
- Low Thermal Resistance Package

Applications

- PA Driver Amplifier
- Cellular, PCS, GSM, UMTS
- IF Amplifier
- Wireless, Data, Satellite

Parameter	Specification			Unit	Oandition	
	Min.	Тур.	Max.	Unit	Condition	
Small Signal Gain	13.0	14.5	16.0	dB	850MHz	
		13.0		dB	1950MHz	
		12.2		dB	2400 MHz	
Output Power at 1dB Compression		12.2		dBm	850MHz	
		11.3		dBm	1950MHz	
Output Third Intercept Point		25.5		dBm	850 MHz	
		24.8		dBm	1950MHz	
Bandwidth Determined by Return Loss (>10dB)		5000		MHz		
Input Return Loss		19.2		dB	1950MHz	
Output Return Loss		22.7		dB	1950MHz	
Noise Figure		3.8		dB	1950MHz	
Device Operating Voltage	2.3	2.6	2.9	V		
Device Operating Current	31	35	39	mA		
Thermal Resistance (Junction - Lead)		97		°C/W		

Test Conditions: $V_S=5V$, $I_D=35$ mA Typ., OIP₃ Tone Spacing=1MHz, P_{OUT} per tone=-5dBm, $R_{BIAS}=68\Omega$, $T_L=25$ °C, $Z_S=Z_L=50\Omega$

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Absolute Maximum Ratings

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Parameter	Rating	Unit
Max Device Current (I _D)	70	mA
Max Device Voltage (V _D)	4	V
Max RF Input Power	+18	dBm
Max Junction Temp (T _J)	+150	°C
Operating Temp Range (TL)	-40 to +85	°C
Max Storage Temp	+150	°C

Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one. Bias Conditions should also satisfy the following expression:

STFOR

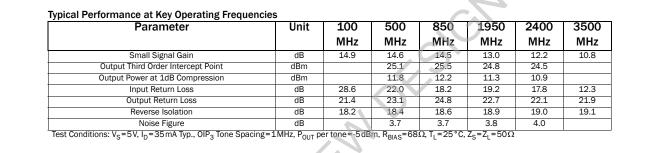
 $I_D V_D < (T_J - T_L) / R_{TH}$, j-l

Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical perfor-mance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

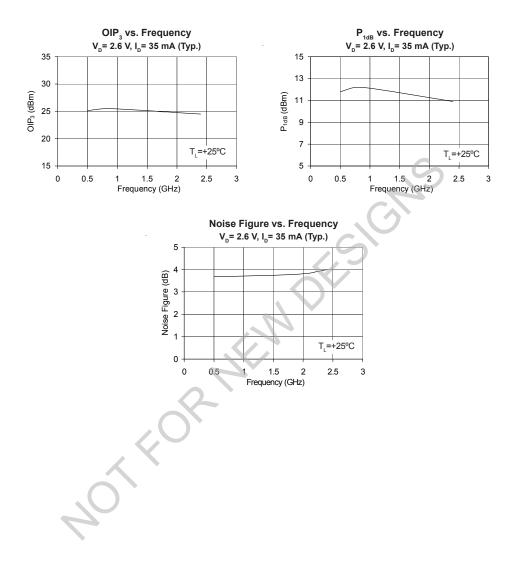
RoHS status based on EUDirective 2002/95/EC (at time of this document revision).

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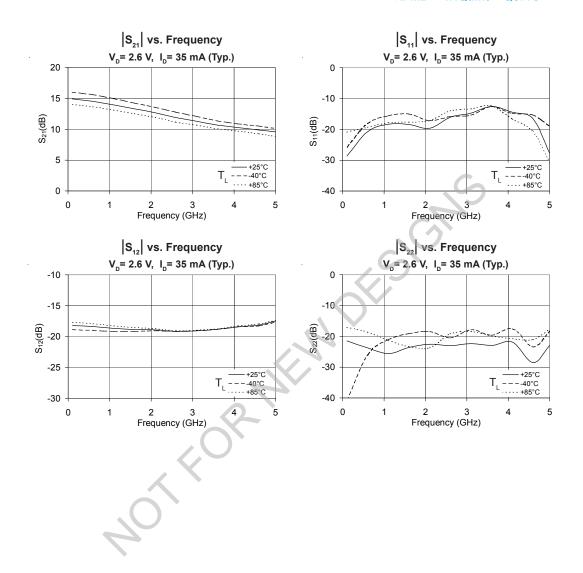


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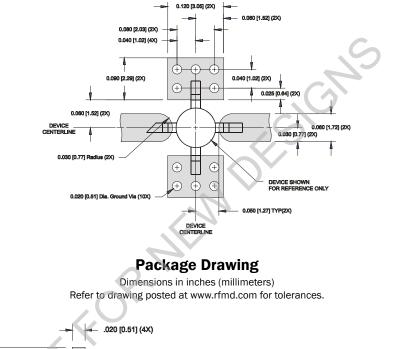


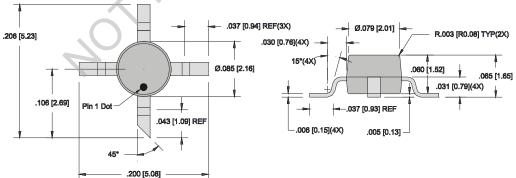




Pin	Function	Description
1	RF IN	RF input pin. This pin requires the use of an external DC-blocking capacitor chosen for the frequency of operation.
2, 4	GND	Connection to ground. For optimum RF performance, use via holes as close to ground leads as possible to reduce lead inductance.
3	RF OUT/BIAS	RF output and bias pin. DC voltage is present on this pin, therefor a DC-blocking capacitor is necessary for proper opera- tion.

Suggested Pad Layout

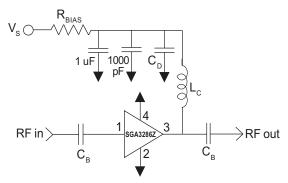






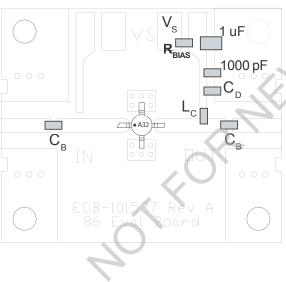


Application Schematic



Reference	Frequency (Mhz)					
Designator	500	850	1950	2400	3500	
C _B	220 pF	100 pF	68 pF	56 pF	39 pF	
C _D	100 pF	68 pF	22 pF	22 pF	15 pF	
L _c	68 nH	33 nH	22 nH	18 nH	15 nH	

Recommended Bias Resistor Values for I _p =35mA R _{BIAS} =(V _S -V _p)/(I _p				
Supply Voltage(V _S)	5 V	8 V	10 V	12 V
R _{BAS}	68 Ω	150 Ω	200 Ω	270 Ω
Note: R _{BMS} provides DC bias stability over temperature.				



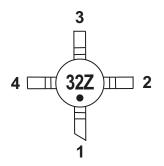
Evaluation Board Layout

Mounting Instructions

- 1. Use a large ground pad area under device pins 2 and 4 with many plated through-holes as shown.
- We recommend 1 or 2 ounce copper. Measurements for this data sheet were made on a 31 mil thick FR-4 board with 1 ounce copper on both sides.



Part Identification



Ordering Information

Ordering Code	Description		
SGA3286Z	13" Reel with 3000 pieces		
SGA3286ZSQ	Sample bag with 25 pieces		
SGA3286ZSR	7" Reel with 100 pieces		
SGA3286ZPCK1	850MHz, 5V Operation PCBA with 5-piece sample bag		
51508			